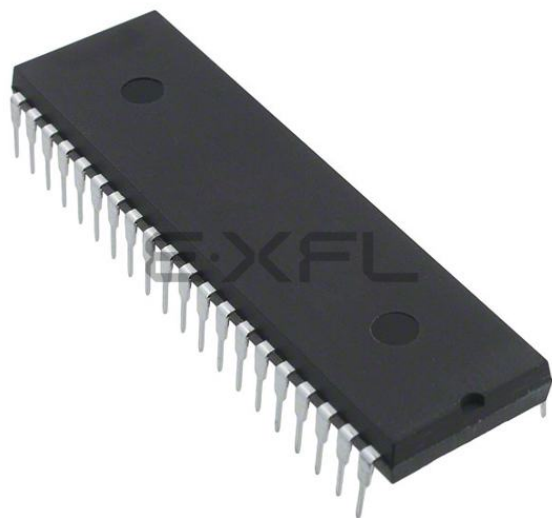




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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	8051
Core Size	8-Bit
Speed	16MHz
Connectivity	EBI/EMI, UART/USART
Peripherals	POR
Number of I/O	32
Program Memory Size	4KB (4K x 8)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	128 x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	-
Oscillator Type	Internal
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Through Hole
Package / Case	40-DIP (0.600", 15.24mm)
Supplier Device Package	40-DIP
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/p87c51sbpn-112

80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

80C51/87C51 ORDERING INFORMATION

	MEMORY SIZE 4K × 8	TEMPERATURE RANGE °C AND PACKAGE	VOLTAGE RANGE	FREQ. (MHz)	DWG. #
ROM	P80C51SBPN	0 to +70, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C51SBPN				
ROM	P80C51SBAA	0 to +70, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C51SBAA				
ROM	P80C51SBBB	0 to +70, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C51SBBB				
ROM	P80C51SFPN	–40 to +85, Plastic Dual In-line Package	2.7 V to 5.5 V	0 to 16	SOT129-1
OTP	P87C51SFPN				
ROM	P80C51SFAA	–40 to +85, Plastic Leaded Chip Carrier	2.7 V to 5.5 V	0 to 16	SOT187-2
OTP	P87C51SFAA				
ROM	P80C51SFBB	–40 to +85, Plastic Quad Flat Pack	2.7 V to 5.5 V	0 to 16	SOT307-2
OTP	P87C51SFBB				
ROM	P80C51UBAA	0 to +70, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C51UBAA				
ROM	P80C51UBPN	0 to +70, Plastic Dual In-line Package	5 V	0 to 33	SOT129-1
OTP	P87C51UBPN				
ROM	P80C51UFAA	–40 to +85, Plastic Leaded Chip Carrier	5 V	0 to 33	SOT187-2
OTP	P87C51UFAA				

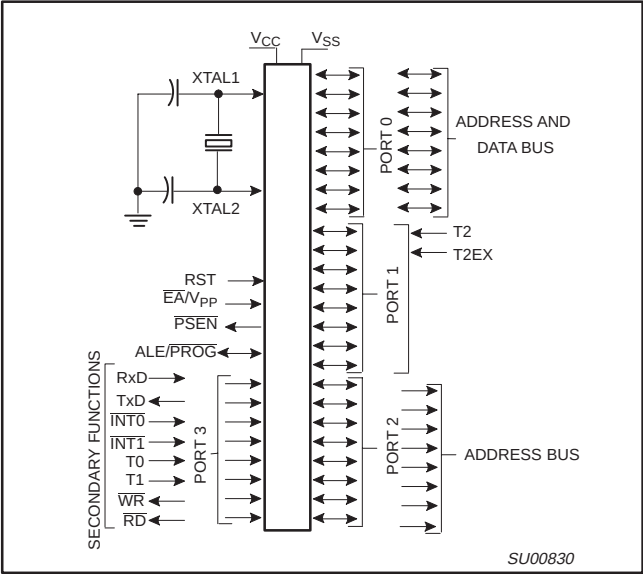
PART NUMBER DERIVATION

DEVICE NUMBER	DEVICE NUMBER	OPERATING FREQUENCY, MAX (S)	TEMPERATURE RANGE (B)	PACKAGE (AA)
ROM	P80C51	S = 16 MHz	B = 0° to +70°C	AA = PLCC
ROM	P80C52	S = 16 MHz	B = 0° to +70°C	AA = PLCC
OTP	P87C51	U = 33 MHz	F = –40°C to +85°C	BB = PQFP
OTP	P87C52	U = 33 MHz	F = –40°C to +85°C	BB = PQFP

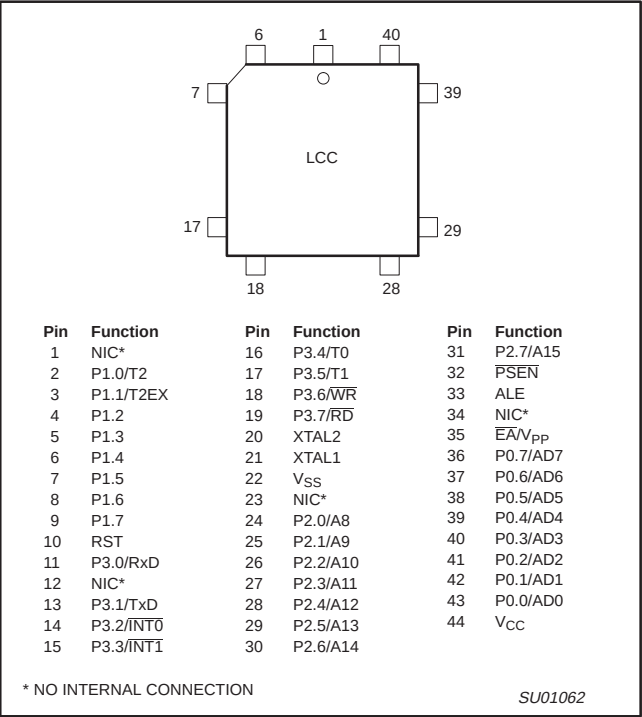
80C51 8-bit microcontroller family
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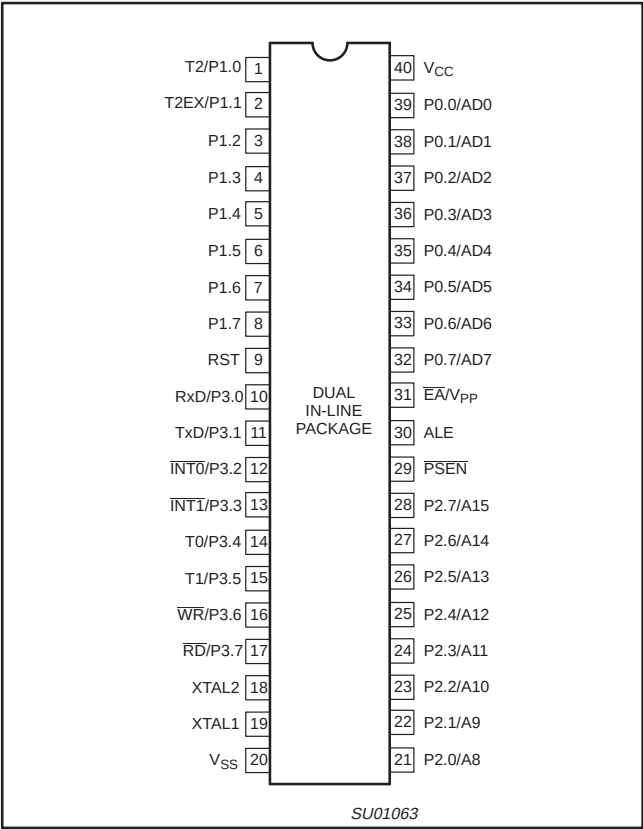
LOGIC SYMBOL



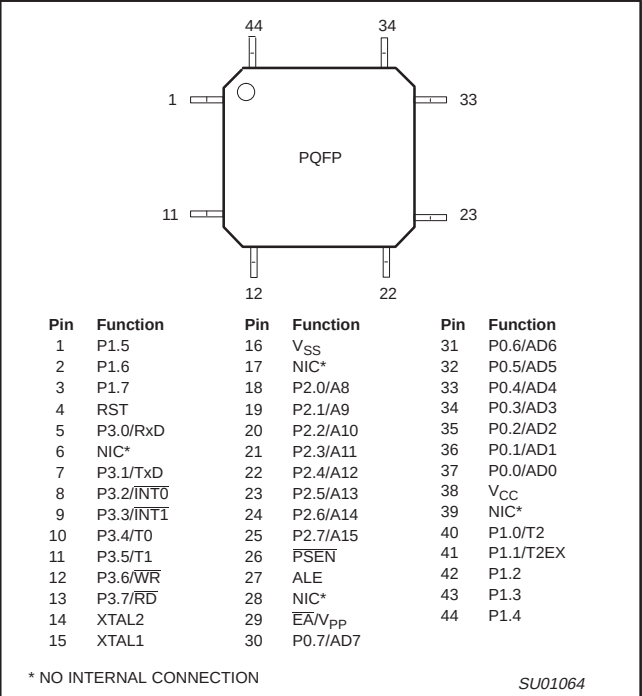
PLASTIC LEADED CHIP CARRIER PIN FUNCTIONS



PIN CONFIGURATIONS



PLASTIC QUAD FLAT PACK
PIN FUNCTIONS



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PIN DESCRIPTIONS

MNEMONIC	PIN NUMBER			TYPE	NAME AND FUNCTION
	DIP	LCC	QFP		
V _{SS}	20	22	16	I	Ground: 0 V reference.
V _{CC}	40	44	38	I	Power Supply: This is the power supply voltage for normal, idle, and power-down operation.
P0.0–P0.7	39–32	43–36	37–30	I/O	Port 0: Port 0 is an open-drain, bidirectional I/O port with Schmitt trigger inputs. Port 0 pins that have 1s written to them float and can be used as high-impedance inputs. Port 0 is also the multiplexed low-order address and data bus during accesses to external program and data memory. In this application, it uses strong internal pull-ups when emitting 1s. Port 0 also outputs the code bytes during program verification and received code bytes during EPROM programming. External pull-ups are required during program verification.
P1.0–P1.7	1–8	2–9	40–44, 1–3	I/O	Port 1: Port 1 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 1 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 1 pins that are externally pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 1 also receives the low-order address byte during program memory verification. Alternate functions for Port 1 include: T2 (P1.0): Timer/Counter 2 external count input/clockout (see Programmable Clock-Out) T2EX (P1.1): Timer/Counter 2 Reload/Capture/Direction control
P2.0–P2.7	21–28	24–31	18–25	I/O	Port 2: Port 2 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 2 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 2 pins that are externally being pulled low will source current because of the internal pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 2 emits the high-order address byte during fetches from external program memory and during accesses to external data memory that use 16-bit addresses (MOVX @DPTR). In this application, it uses strong internal pull-ups when emitting 1s. During accesses to external data memory that use 8-bit addresses (MOV @Ri), port 2 emits the contents of the P2 special function register. Some Port 2 pins receive the high order address bits during EPROM programming and verification.
P3.0–P3.7	10–17	11, 13–19	5, 7–13	I/O	Port 3: Port 3 is an 8-bit bidirectional I/O port with internal pull-ups and Schmitt trigger inputs. Port 3 pins that have 1s written to them are pulled high by the internal pull-ups and can be used as inputs. As inputs, port 3 pins that are externally being pulled low will source current because of the pull-ups. (See DC Electrical Characteristics: I _{IL}). Port 3 also serves the special features of the 80C51 family, as listed below: RxD (P3.0): Serial input port TxD (P3.1): Serial output port INT0 (P3.2): External interrupt INT1 (P3.3): External interrupt T0 (P3.4): Timer 0 external input T1 (P3.5): Timer 1 external input WR (P3.6): External data memory write strobe RD (P3.7): External data memory read strobe
RST	9	10	4	I	Reset: A high on this pin for two machine cycles while the oscillator is running, resets the device. An internal diffused resistor to V _{SS} permits a power-on reset using only an external capacitor to V _{CC} .
ALE/PROG	30	33	27	O	Address Latch Enable/Program Pulse: Output pulse for latching the low byte of the address during an access to external memory. In normal operation, ALE is emitted at a constant rate of 1/6 the oscillator frequency, and can be used for external timing or clocking. Note that one ALE pulse is skipped during each access to external data memory. This pin is also the program pulse input (PROG) during EPROM programming. ALE can be disabled by setting SFR auxiliary.0. With this bit set, ALE will be active only during a MOVX instruction.
PSEN	29	32	26	O	Program Store Enable: The read strobe to external program memory. When the device is executing code from the external program memory, PSEN is activated twice each machine cycle, except that two PSEN activations are skipped during each access to external data memory. PSEN is not activated during fetches from internal program memory.
EA/V _{PP}	31	35	29	I	External Access Enable/Programming Supply Voltage: EA must be externally held low to enable the device to fetch code from external program memory locations 0000H to 0FFFFH. If EA is held high, the device executes from internal program memory unless the program counter contains an address greater than the on-chip ROM/OTP. This pin also receives the 12.75 V programming supply voltage (V _{PP}) during EPROM programming. If security bit 1 is programmed, EA will be internally latched on Reset.
XTAL1	19	21	15	I	Crystal 1: Input to the inverting oscillator amplifier and input to the internal clock generator circuits.
XTAL2	18	20	14	O	Crystal 2: Output from the inverting oscillator amplifier.

NOTE:

To avoid "latch-up" effect at power-on, the voltage on any pin at any time must not be higher than V_{CC} + 0.5 V or V_{SS} – 0.5 V, respectively.

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OSCILLATOR CHARACTERISTICS

XTAL1 and XTAL2 are the input and output, respectively, of an inverting amplifier. The pins can be configured for use as an on-chip oscillator, as shown in the logic symbol.

To drive the device from an external clock source, XTAL1 should be driven while XTAL2 is left unconnected. There are no requirements on the duty cycle of the external clock signal, because the input to the internal clock circuitry is through a divide-by-two flip-flop. However, minimum and maximum high and low times specified in the data sheet must be observed.

Reset

A reset is accomplished by holding the RST pin high for at least two machine cycles (24 oscillator periods), while the oscillator is running. To insure a good power-up reset, the RST pin must be high long enough to allow the oscillator time to start up (normally a few milliseconds) plus two machine cycles.

Stop Clock Mode

The static design enables the clock speed to be reduced down to 0 MHz (stopped). When the oscillator is stopped, the RAM and Special Function Registers retain their values. This mode allows step-by-step utilization and permits reduced system power consumption by lowering the clock frequency down to any value. For lowest power consumption the Power Down mode is suggested.

Idle Mode

In idle mode (see Table 2), the CPU puts itself to sleep while all of the on-chip peripherals stay active. The instruction to invoke the idle mode is the last instruction executed in the normal operating mode before the idle mode is activated. The CPU contents, the on-chip RAM, and all of the special function registers remain intact during this mode. The idle mode can be terminated either by any enabled interrupt (at which time the process is picked up at the interrupt service routine and continued), or by a hardware reset which starts the processor in the same manner as a power-on reset.

Power-Down Mode

To save even more power, a Power Down mode (see Table 2) can be invoked by software. In this mode, the oscillator is stopped and the instruction that invoked Power Down is the last instruction executed. The on-chip RAM and Special Function Registers retain their values down to 2.0 V and care must be taken to return V_{CC} to the minimum specified operating voltages before the Power Down Mode is terminated.

For the 87C51 and 80C51 either a hardware reset or external interrupt can be used to exit from Power Down. Reset redefines all

the SFRs but does not change the on-chip RAM. An external interrupt allows both the SFRs and the on-chip RAM to retain their values. WUPD (AUXR1.3–Wakeup from Power Down) enables or disables the wakeup from power down with external interrupt.

Where:

WUPD = 0 Disable

WUPD = 1 Enable

To properly terminate Power Down the reset or external interrupt should not be executed before V_{CC} is restored to its normal operating level and must be held active long enough for the oscillator to restart and stabilize (normally less than 10 ms).

With an external interrupt, INT0 or INT1 must be enabled and configured as level-sensitive. Holding the pin low restarts the oscillator but bringing the pin back high completes the exit. Once the interrupt is serviced, the next instruction to be executed after RETI will be the one following the instruction that put the device into Power Down.

LPEP

The eeprom array contains some analog circuits that are not required when V_{CC} is less than 4 V, but are required for a V_{CC} greater than 4 V. The LPEP bit (AUXR.4), when set, will powerdown these analog circuits resulting in a reduced supply current. This bit should be set ONLY for applications that operate at a V_{CC} less than 4 V.

Design Consideration

- When the idle mode is terminated by a hardware reset, the device normally resumes program execution, from where it left off, up to two machine cycles before the internal reset algorithm takes control. On-chip hardware inhibits access to internal RAM in this event, but access to the port pins is not inhibited. To eliminate the possibility of an unexpected write when Idle is terminated by reset, the instruction following the one that invokes Idle should not be one that writes to a port pin or to external memory.

ONCE™ Mode

The ONCE ("On-Circuit Emulation") Mode facilitates testing and debugging of systems without the device having to be removed from the circuit. The ONCE Mode is invoked by:

- Pull ALE low while the device is in reset and $\overline{PSEN}$ is high;
- Hold ALE low as RST is deactivated.

While the device is in ONCE Mode, the Port 0 pins go into a float state, and the other port pins and ALE and $\overline{PSEN}$ are weakly pulled high. The oscillator circuit remains active. While the device is in this mode, an emulator or test CPU can be used to drive the circuit. Normal operation is restored when a normal reset is applied.

Table 2. External Pin Status During Idle and Power-Down Modes

MODE	PROGRAM MEMORY	ALE	$\overline{PSEN}$	PORT 0	PORT 1	PORT 2	PORT 3
Idle	Internal	1	1	Data	Data	Data	Data
Idle	External	1	1	Float	Data	Address	Data
Power-down	Internal	0	0	Data	Data	Data	Data
Power-down	External	0	0	Float	Data	Data	Data

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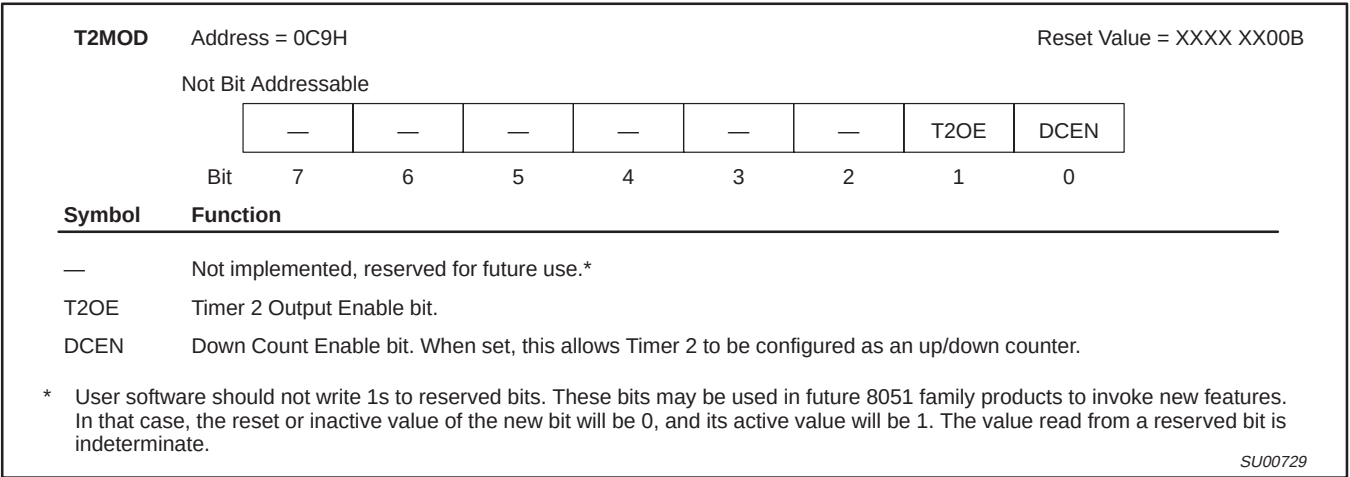


Figure 3. Timer 2 Mode (T2MOD) Control Register

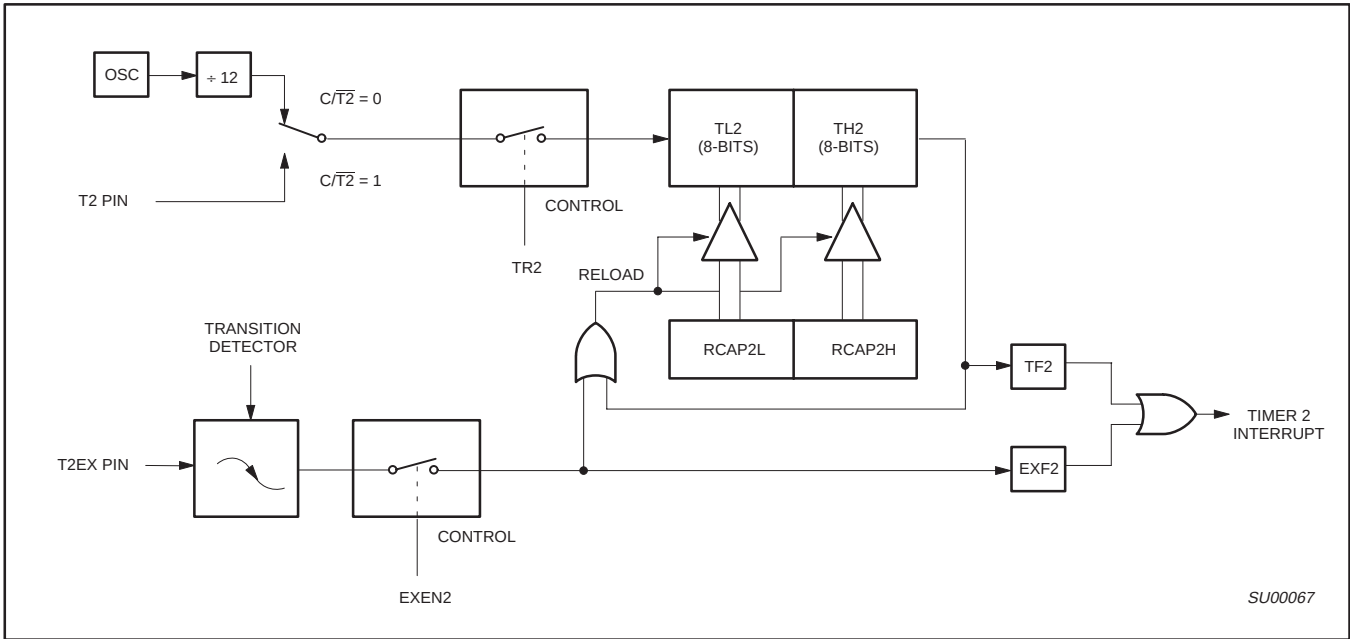


Figure 4. Timer 2 in Auto-Reload Mode (DCEN = 0)

80C51/87C51/80C52/87C52



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Baud Rate Generator Mode

Bits TCLK and/or RCLK in T2CON (Table 3) allow the serial port transmit and receive baud rates to be derived from either Timer 1 or Timer 2. When TCLK= 0, Timer 1 is used as the serial port transmit baud rate generator. When TCLK= 1, Timer 2 is used as the serial port transmit baud rate generator. RCLK has the same effect for the serial port receive baud rate. With these two bits, the serial port can have different receive and transmit baud rates – one generated by Timer 1, the other by Timer 2.

Figure 6 shows the Timer 2 in baud rate generation mode. The baud rate generation mode is like the auto-reload mode, in that a rollover in TH2 causes the Timer 2 registers to be reloaded with the 16-bit value in registers RCAP2H and RCAP2L, which are preset by software.

The baud rates in modes 1 and 3 are determined by Timer 2's overflow rate given below:

$$\text{Modes 1 and 3 Baud Rates} = \frac{\text{Timer 2 Overflow Rate}}{16}$$

The timer can be configured for either "timer" or "counter" operation. In many applications, it is configured for "timer" operation ($C/\overline{T2}=0$). Timer operation is different for Timer 2 when it is being used as a baud rate generator.

Usually, as a timer it would increment every machine cycle (i.e., 1/12 the oscillator frequency). As a baud rate generator, it increments every state time (i.e., 1/2 the oscillator frequency). Thus the baud rate formula is as follows:

$$\text{Modes 1 and 3 Baud Rates} = \frac{\text{Oscillator Frequency}}{[32 \times [65536 - (\text{RCAP2H}, \text{RCAP2L})]]}$$

Where: (RCAP2H, RCAP2L)= The content of RCAP2H and RCAP2L taken as a 16-bit unsigned integer.

The Timer 2 as a baud rate generator mode shown in Figure 6, is valid only if RCLK and/or TCLK = 1 in T2CON register. Note that a rollover in TH2 does not set TF2, and will not generate an interrupt. Thus, the Timer 2 interrupt does not have to be disabled when Timer 2 is in the baud rate generator mode. Also if the EXEN2 (T2 external enable flag) is set, a 1-to-0 transition in T2EX (Timer/counter 2 trigger input) will set EXF2 (T2 external flag) but will not cause a reload from (RCAP2H, RCAP2L) to (TH2, TL2). Therefore when Timer 2 is in use as a baud rate generator, T2EX can be used as an additional external interrupt, if needed.

When Timer 2 is in the baud rate generator mode, one should not try to read or write TH2 and TL2. As a baud rate generator, Timer 2 is incremented every state time (osc/2) or asynchronously from pin T2;

under these conditions, a read or write of TH2 or TL2 may not be accurate. The RCAP2 registers may be read, but should not be written to, because a write might overlap a reload and cause write and/or reload errors. The timer should be turned off (clear TR2) before accessing the Timer 2 or RCAP2 registers.

Table 4 shows commonly used baud rates and how they can be obtained from Timer 2.

Table 4. Timer 2 Generated Commonly Used Baud Rates

Baud Rate	Osc Freq	Timer 2	
		RCAP2H	RCAP2L
375 K	12 MHz	FF	FF
9.6 K	12 MHz	FF	D9
2.8 K	12 MHz	FF	B2
2.4 K	12 MHz	FF	64
1.2 K	12 MHz	FE	C8
300	12 MHz	FB	1E
110	12 MHz	F2	AF
300	6 MHz	FD	8F
110	6 MHz	F9	57

Summary Of Baud Rate Equations

Timer 2 is in baud rate generating mode. If Timer 2 is being clocked through pin T2(P1.0) the baud rate is:

$$\text{Baud Rate} = \frac{\text{Timer 2 Overflow Rate}}{16}$$

If Timer 2 is being clocked internally, the baud rate is:

$$\text{Baud Rate} = \frac{f_{\text{osc}}}{[32 \times [65536 - (\text{RCAP2H}, \text{RCAP2L})]]}$$

Where f_{osc} = Oscillator Frequency

To obtain the reload value for RCAP2H and RCAP2L, the above equation can be rewritten as:

$$\text{RCAP2H, RCAP2L} = 65536 - \left(\frac{f_{\text{osc}}}{32 \times \text{Baud Rate}} \right)$$

Timer/Counter 2 Set-up

Except for the baud rate generator mode, the values given for T2CON do not include the setting of the TR2 bit. Therefore, bit TR2 must be set, separately, to turn the timer on. See Table 5 for set-up of Timer 2 as a timer. Also see Table 6 for set-up of Timer 2 as a counter.

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Reduced EMI

All port pins of the 8xC51 and 8xC52 have slew rate controlled outputs. This is to limit noise generated by quickly switching output signals. The slew rate is factory set to approximately 10 ns rise and fall times.

Reduced EMI Mode

The AO bit (AUXR.0) in the AUXR register when set disables the ALE output.

AUXR (8EH)

7	6	5	4	3	2	1	0
–	–	–	–	–	–	–	AO
AUXR.0		AO		Turns off ALE output.			

Dual DPTR

The dual DPTR structure (see Figure 13) enables a way to specify the address of an external data memory location. There are two 16-bit DPTR registers that address the external memory, and a single bit called DPS = AUXR1/bit0 that allows the program code to switch between them.

- New Register Name: AUXR1#
- SFR Address: A2H
- Reset Value: xxx000x0B

AUXR1 (A2H)

7	6	5	4	3	2	1	0
–	–	–	LPEP	WUPD	0	–	DPS

Where:
DPS = AUXR1/bit0 = Switches between DPTR0 and DPTR1.

Select Reg	DPS
DPTR0	0
DPTR1	1

The DPS bit status should be saved by software when switching between DPTR0 and DPTR1.

Note that bit 2 is not writable and is always read as a zero. This allows the DPS bit to be quickly toggled simply by executing an INC DPTR instruction without affecting the WOPD or LPEP bits.

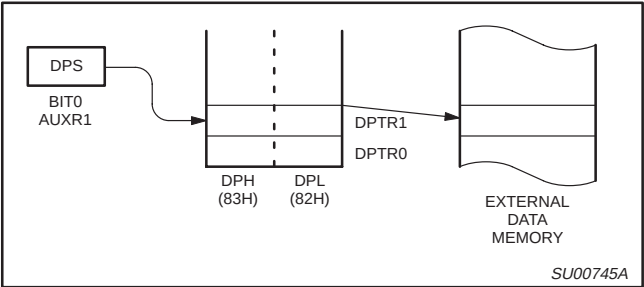


Figure 13.

DPTR Instructions

The instructions that refer to DPTR refer to the data pointer that is currently selected using the AUXR1/bit 0 register. The six instructions that use the DPTR are as follows:

INC DPTR	Increments the data pointer by 1
MOV DPTR, #data16	Loads the DPTR with a 16-bit constant
MOV A, @ A+DPTR	Move code byte relative to DPTR to ACC
MOVX A, @ DPTR	Move external RAM (16-bit address) to ACC
MOVX @ DPTR, A	Move ACC to external RAM (16-bit address)
JMP @ A + DPTR	Jump indirect relative to DPTR

The data pointer can be accessed on a byte-by-byte basis by specifying the low or high byte in an instruction which accesses the SFRs. See application note AN458 for more details.

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DC ELECTRICAL CHARACTERISTICS

$T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ or -40°C to $+85^{\circ}\text{C}$, $V_{CC} = 2.7\text{ V}$ to 5.5 V , $V_{SS} = 0\text{ V}$ (16 MHz devices)

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP ¹	MAX	
V_{IL}	Input low voltage ¹¹	$4.0\text{ V} < V_{CC} < 5.5\text{ V}$	-0.5		$0.2 V_{CC} - 0.1$	V
		$2.7\text{ V} < V_{CC} < 4.0\text{ V}$	-0.5		0.7	V
V_{IH}	Input high voltage (ports 0, 1, 2, 3, $\overline{\text{EA}}$)		$0.2 V_{CC} + 0.9$		$V_{CC} + 0.5$	V
V_{IH1}	Input high voltage, XTAL1, RST ¹¹		$0.7 V_{CC}$		$V_{CC} + 0.5$	V
V_{OL}	Output low voltage, ports 1, 2, ⁸	$V_{CC} = 2.7\text{ V}$ $I_{OL} = 1.6\text{ mA}^2$			0.4	V
V_{OL1}	Output low voltage, port 0, ALE, $\overline{\text{PSEN}}^8, ^7$	$V_{CC} = 2.7\text{ V}$ $I_{OL} = 3.2\text{ mA}^2$			0.4	V
V_{OH}	Output high voltage, ports 1, 2, 3 ³	$V_{CC} = 2.7\text{ V}$ $I_{OH} = -20\text{ }\mu\text{A}$	$V_{CC} - 0.7$			V
		$V_{CC} = 4.5\text{ V}$ $I_{OH} = -30\text{ }\mu\text{A}$	$V_{CC} - 0.7$			V
V_{OH1}	Output high voltage (port 0 in external bus mode), ALE ⁹ , $\overline{\text{PSEN}}^3$	$V_{CC} = 2.7\text{ V}$ $I_{OH} = -3.2\text{ mA}$	$V_{CC} - 0.7$			V
I_{IL}	Logical 0 input current, ports 1, 2, 3	$V_{IN} = 0.4\text{ V}$	-1		-50	μA
I_{TL}	Logical 1-to-0 transition current, ports 1, 2, 3 ⁶	$V_{IN} = 2.0\text{ V}$ See note 4			-650	μA
I_{LI}	Input leakage current, port 0	$0.45 < V_{IN} < V_{CC} - 0.3$			± 10	μA
I_{CC}	Power supply current (see Figure 21): Active mode @ 16 MHz Idle mode @ 16 MHz Power-down mode or clock stopped (see Figure 25 for conditions)	See note 5 $T_{amb} = 0^{\circ}\text{C}$ to 70°C $T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$		3		μA
					50 75	μA μA
R_{RST}	Internal reset pull-down resistor		40		225	k Ω
C_{IO}	Pin capacitance ¹⁰ (except $\overline{\text{EA}}$)				15	pF

NOTES:

- Typical ratings are not guaranteed. The values listed are at room temperature, 5 V.
- Capacitive loading on ports 0 and 2 may cause spurious noise to be superimposed on the V_{OL} s of ALE and ports 1 and 3. The noise is due to external bus capacitance discharging into the port 0 and port 2 pins when these pins make 1-to-0 transitions during bus operations. In the worst cases (capacitive loading $> 100\text{ pF}$), the noise pulse on the ALE pin may exceed 0.8 V. In such cases, it may be desirable to qualify ALE with a Schmitt Trigger, or use an address latch with a Schmitt Trigger STROBE input. I_{OL} can exceed these conditions provided that no single output sinks more than 5 mA and no more than two outputs exceed the test conditions.
- Capacitive loading on ports 0 and 2 may cause the V_{OH} on ALE and $\overline{\text{PSEN}}$ to momentarily fall below the $V_{CC} - 0.7$ specification when the address bits are stabilizing.
- Pins of ports 1, 2 and 3 source a transition current when they are being externally driven from 1 to 0. The transition current reaches its maximum value when V_{IN} is approximately 2 V.
- See Figures 22 through 25 for I_{CC} test conditions.
Active mode: $I_{CC} = 0.9 \times \text{FREQ.} + 1.1\text{ mA}$
Idle mode: $I_{CC} = 0.18 \times \text{FREQ.} + 1.01\text{ mA}$; See Figure 21.
- This value applies to $T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$. For $T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $I_{TL} = -750\text{ }\mu\text{A}$.
- Load capacitance for port 0, ALE, and $\overline{\text{PSEN}} = 100\text{ pF}$, load capacitance for all other outputs = 80 pF.
- Under steady state (non-transient) conditions, I_{OL} must be externally limited as follows:
Maximum I_{OL} per port pin: 15 mA (*NOTE: This is 85°C specification.)
Maximum I_{OL} per 8-bit port: 26 mA
Maximum total I_{OL} for all outputs: 71 mA
If I_{OL} exceeds the test condition, V_{OL} may exceed the related specification. Pins are not guaranteed to sink current greater than the listed test conditions.
- ALE is tested to V_{OH1} , except when ALE is off then V_{OH} is the voltage specification.
- Pin capacitance is characterized but not tested. Pin capacitance is less than 25 pF. Pin capacitance of ceramic package is less than 15 pF (except $\overline{\text{EA}}$ is 25 pF).
- To improve noise rejection a nominal 100 ns glitch rejection circuitry has been added to the RST pin, and a nominal 15 ns glitch rejection circuitry has been added to the INT0 and INT1 pins. Previous devices provided only an inherent 5 ns of glitch rejection.

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

AC ELECTRICAL CHARACTERISTICS

$T_{amb} = 0^{\circ}\text{C}$ to $+70^{\circ}\text{C}$ or -40°C to $+85^{\circ}\text{C}$, $V_{CC} = 5\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}^{1, 2, 3}$

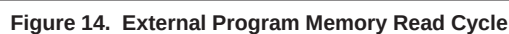
SYMBOL	FIGURE	PARAMETER	VARIABLE CLOCK ⁴ 16 MHz to f_{max}		33 MHz ζ CLOCK		UNIT
			MIN	MAX	MIN	MAX	
t_{HLL}	14	ALE pulse width	$2t_{CLCL}-40$		21		ns
t_{AVLL}	14	Address valid to ALE low	$t_{CLCL}-25$		5		ns
t_{LLAX}	14	Address hold after ALE low	$t_{CLCL}-25$				ns
t_{LLIV}	14	ALE low to valid instruction in		$4t_{CLCL}-65$		55	ns
t_{LLPL}	14	ALE low to $\overline{\text{PSEN}}$ low	$t_{CLCL}-25$		5		ns
t_{PLPH}	14	$\overline{\text{PSEN}}$ pulse width	$3t_{CLCL}-45$		45		ns
t_{PLIV}	14	$\overline{\text{PSEN}}$ low to valid instruction in		$3t_{CLCL}-60$		30	ns
t_{PXIX}	14	Input instruction hold after $\overline{\text{PSEN}}$	0		0		ns
t_{PXIZ}	14	Input instruction float after $\overline{\text{PSEN}}$		$t_{CLCL}-25$		5	ns
t_{AVIV}	14	Address to valid instruction in		$5t_{CLCL}-80$		70	ns
t_{PLAZ}	14	$\overline{\text{PSEN}}$ low to address float		10		10	ns
Data Memory							
t_{RLRH}	15, 16	$\overline{\text{RD}}$ pulse width	$6t_{CLCL}-100$		82		ns
t_{WLWH}	15, 16	$\overline{\text{WR}}$ pulse width	$6t_{CLCL}-100$		82		ns
t_{RLDV}	15, 16	$\overline{\text{RD}}$ low to valid data in		$5t_{CLCL}-90$		60	ns
t_{RHDX}	15, 16	Data hold after $\overline{\text{RD}}$	0		0		ns
t_{RHDZ}	15, 16	Data float after $\overline{\text{RD}}$		$2t_{CLCL}-28$		32	ns
t_{LLDV}	15, 16	ALE low to valid data in		$8t_{CLCL}-150$		90	ns
t_{AVDV}	15, 16	Address to valid data in		$9t_{CLCL}-165$		105	ns
t_{LLWL}	15, 16	ALE low to $\overline{\text{RD}}$ or $\overline{\text{WR}}$ low	$3t_{CLCL}-50$	$3t_{CLCL}+50$	40	140	ns
t_{AVWL}	15, 16	Address valid to $\overline{\text{WR}}$ low or $\overline{\text{RD}}$ low	$4t_{CLCL}-75$		45		ns
t_{QVWX}	15, 16	Data valid to $\overline{\text{WR}}$ transition	$t_{CLCL}-30$		0		ns
t_{WHQX}	15, 16	Data hold after $\overline{\text{WR}}$	$t_{CLCL}-25$		5		ns
t_{QVWH}	16	Data valid to $\overline{\text{WR}}$ high	$7t_{CLCL}-130$		80		ns
t_{RLAZ}	15, 16	$\overline{\text{RD}}$ low to address float		0		0	ns
t_{WHLH}	15, 16	$\overline{\text{RD}}$ or $\overline{\text{WR}}$ high to ALE high	$t_{CLCL}-25$	$t_{CLCL}+25$	5	55	ns
External Clock							
t_{CHCX}	18	High time	$0.38t_{CLCL}$	$t_{CLCL}-t_{CLCX}$			ns
t_{CLCX}	18	Low time	$0.38t_{CLCL}$	$t_{CLCL}-t_{CHCX}$			ns
t_{CLCH}	18	Rise time		5			ns
t_{CHCL}	18	Fall time		5			ns
Shift Register							
t_{XLXL}	17	Serial port clock cycle time	$12t_{CLCL}$		360		ns
t_{QVXH}	17	Output data setup to clock rising edge	$10t_{CLCL}-133$		167		ns
t_{XHQX}	17	Output data hold after clock rising edge	$2t_{CLCL}-80$				ns
t_{XHDX}	17	Input data hold after clock rising edge	0		0		ns
t_{XHDV}	17	Clock rising edge to input data valid		$10t_{CLCL}-133$		167	ns

NOTES:

- Parameters are valid over operating temperature range unless otherwise specified.
- Load capacitance for port 0, ALE, and $\overline{\text{PSEN}}$ = 100 pF, load capacitance for all other outputs = 80 pF.
- Interfacing the 87C51, 80C51, 87C52 or 80C52 to devices with float times up to 45ns is permitted. This limited bus contention will not cause damage to Port 0 drivers.
- Variable clock is specified for oscillator frequencies greater than 16 MHz to 33 MHz. For frequencies equal or less than 16 MHz, see 16 MHz "AC Electrical Characteristics", page 24.
- Parts are guaranteed to operate down to 0 Hz. When an external clock source is used, the RST pin should be held high for a minimum of 20 μs for power-on or wakeup from power down.

80C51/87C51/80C52/87C52

Examples: t_{AVLL} = Time for address valid to ALE low.
 t_{LLPL} = Time for ALE low to $\overline{PSEN}$ low.



80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

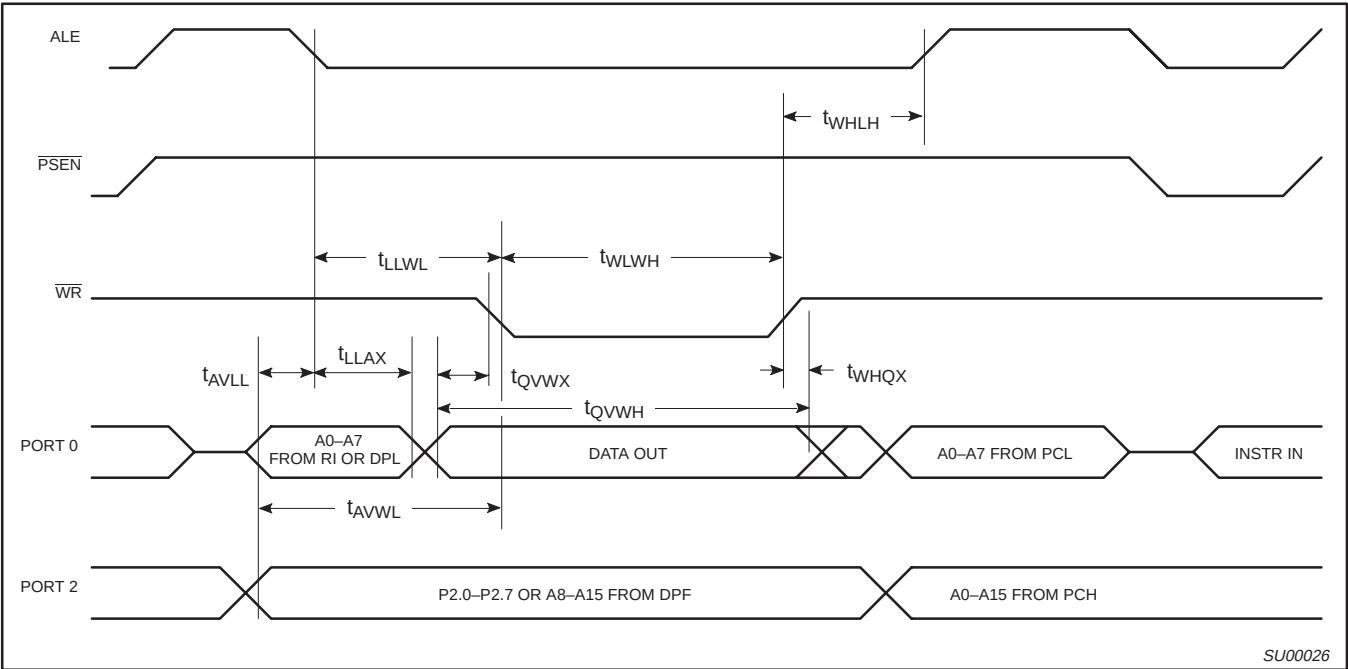


Figure 16. External Data Memory Write Cycle

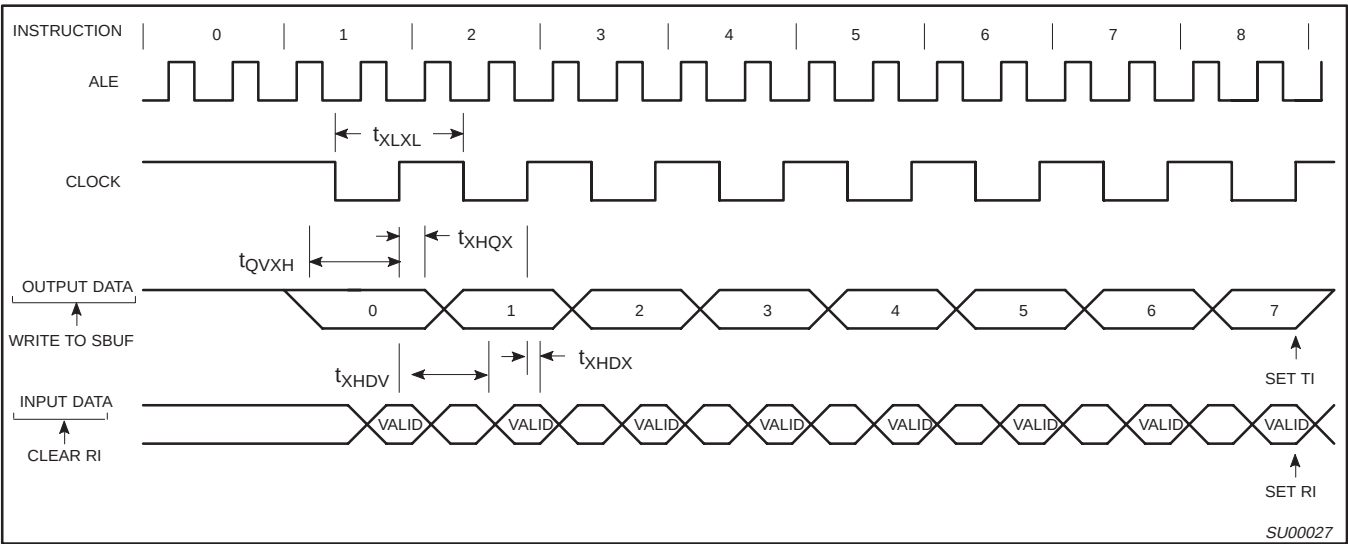


Figure 17. Shift Register Mode Timing

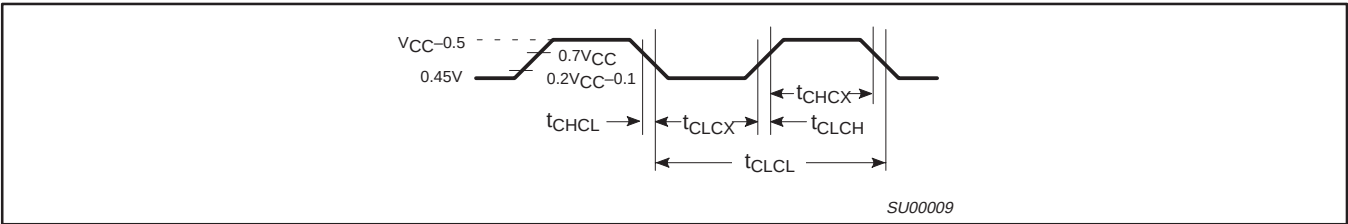


Figure 18. External Clock Drive

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

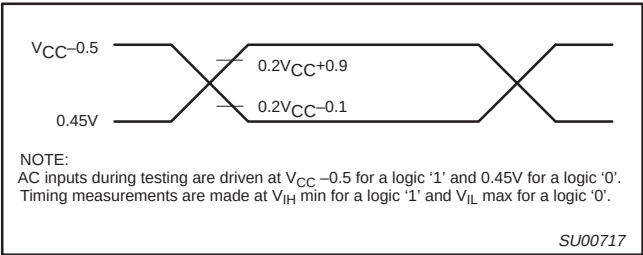


Figure 19. AC Testing Input/Output

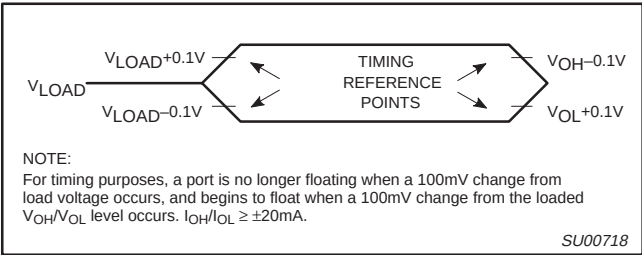


Figure 20. Float Waveform

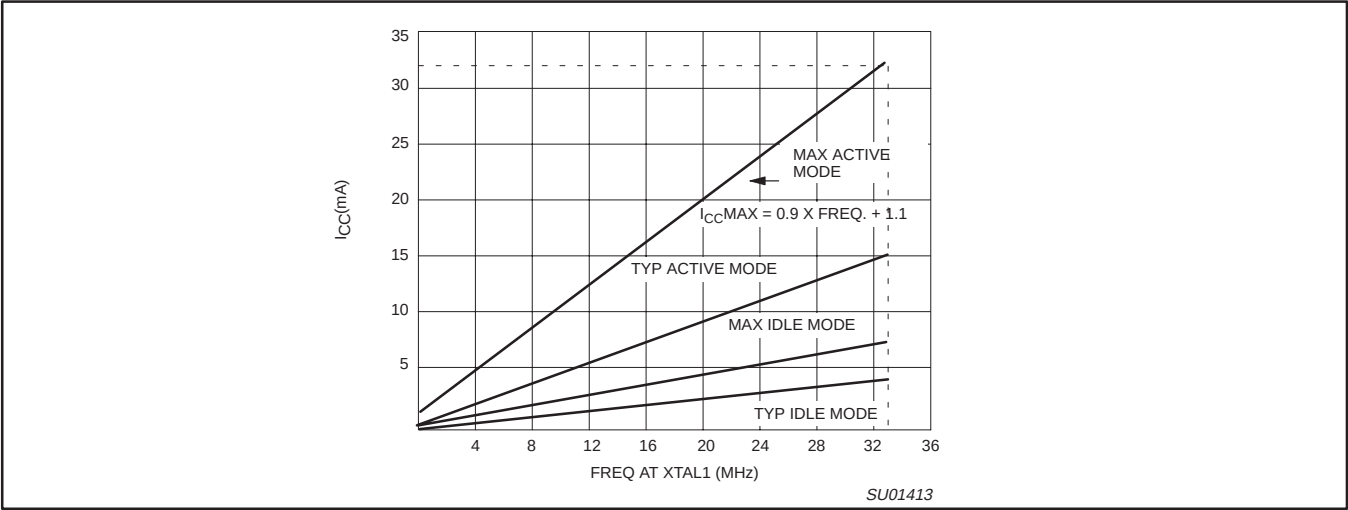


Figure 21. I_{CC} vs. FREQ
Valid only within frequency specifications of the device under test

80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

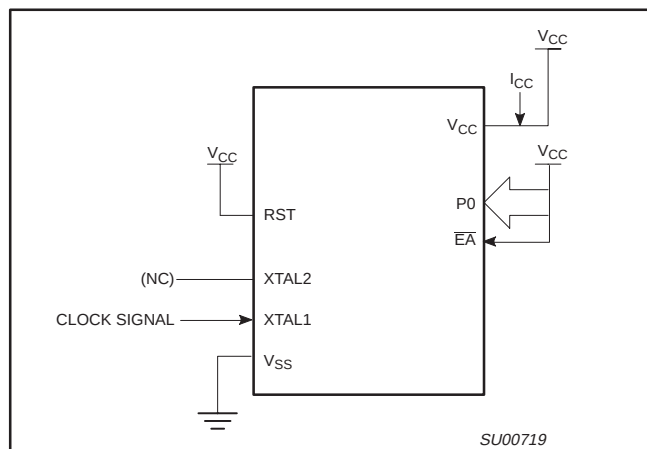


Figure 22. I_{CC} Test Condition, Active Mode
 All other pins are disconnected

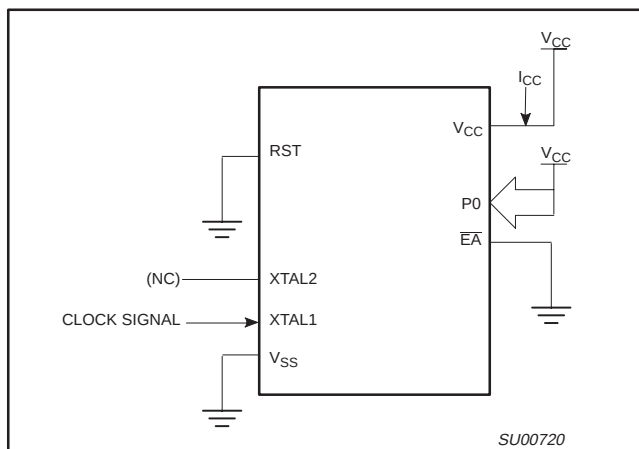


Figure 23. I_{CC} Test Condition, Idle Mode
 All other pins are disconnected

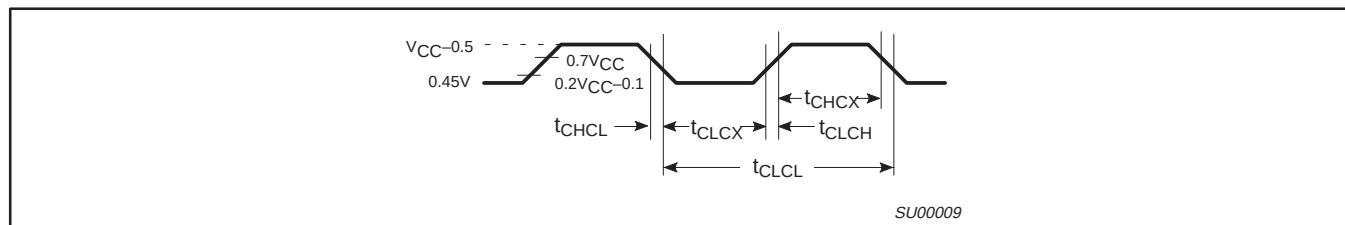


Figure 24. Clock Signal Waveform for I_{CC} Tests in Active and Idle Modes
 $t_{CLCH} = t_{CHCL} = 5\text{ns}$

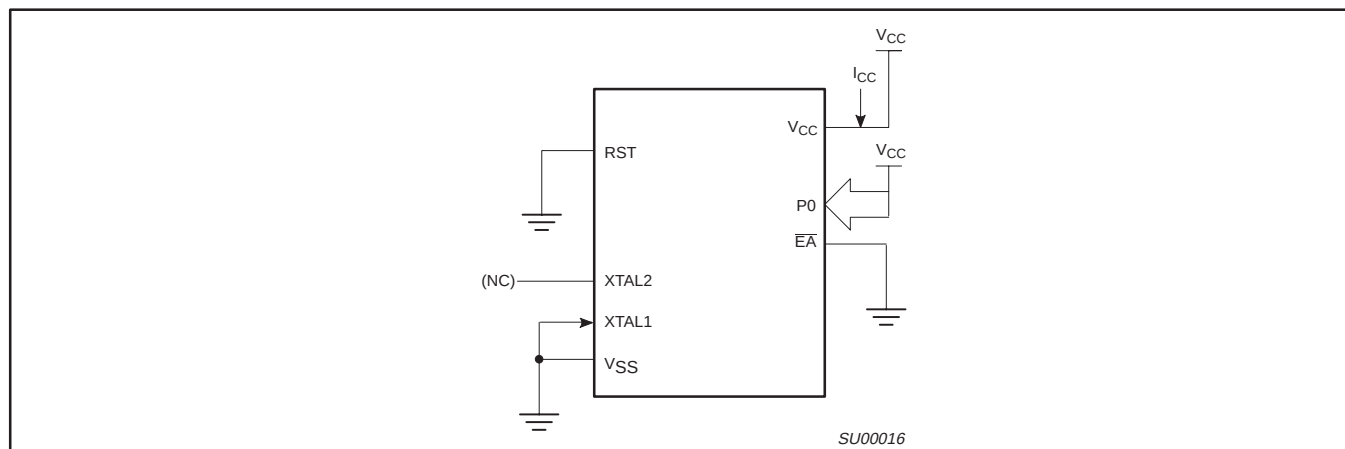


Figure 25. I_{CC} Test Condition, Power Down Mode
 All other pins are disconnected. $V_{CC} = 2\text{ V to } 5.5\text{ V}$

80C51 8-bit microcontroller family

4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V), low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

EPROM CHARACTERISTICS

These devices can be programmed by using a modified Improved Quick-Pulse Programming™ algorithm. It differs from older methods in the value used for V_{PP} (programming supply voltage) and in the width and number of the ALE/PROG pulses.

The family contains two signature bytes that can be read and used by an EPROM programming system to identify the device. The signature bytes identify the device as being manufactured by Philips.

Table 8 shows the logic levels for reading the signature byte, and for programming the program memory, the encryption table, and the security bits. The circuit configuration and waveforms for quick-pulse programming are shown in Figures 26 and 27. Figure 28 shows the circuit configuration for normal program memory verification.

Quick-Pulse Programming

The setup for microcontroller quick-pulse programming is shown in Figure 26. Note that the device is running with a 4 to 6 MHz oscillator. The reason the oscillator needs to be running is that the device is executing internal address and program data transfers.

The address of the EPROM location to be programmed is applied to ports 1 and 2, as shown in Figure 26. The code byte to be programmed into that location is applied to port 0. RST, $\overline{PSEN}$ and pins of ports 2 and 3 specified in Table 8 are held at the 'Program Code Data' levels indicated in Table 8. The ALE/PROG is pulsed low 5 times as shown in Figure 27.

To program the encryption table, repeat the 5 pulse programming sequence for addresses 0 through 1FH, using the 'Pgm Encryption Table' levels. Do not forget that after the encryption table is programmed, verification cycles will produce only encrypted data.

To program the security bits, repeat the 5 pulse programming sequence using the 'Pgm Security Bit' levels. After one security bit is programmed, further programming of the code memory and encryption table is disabled. However, the other security bits can still be programmed.

Note that the $\overline{EA}/V_{PP}$ pin must not be allowed to go above the maximum specified V_{PP} level for any amount of time. Even a narrow glitch above that voltage can cause permanent damage to the

device. The V_{PP} source should be well regulated and free of glitches and overshoot.

Program Verification

If security bits 2 and 3 have not been programmed, the on-chip program memory can be read out for program verification. The address of the program memory locations to be read is applied to ports 1 and 2 as shown in Figure 28. The other pins are held at the 'Verify Code Data' levels indicated in Table 8. The contents of the address location will be emitted on port 0. External pull-ups are required on port 0 for this operation.

If the 64 byte encryption table has been programmed, the data presented at port 0 will be the exclusive NOR of the program byte with one of the encryption bytes. The user will have to know the encryption table contents in order to correctly decode the verification data. The encryption table itself cannot be read out.

Reading the Signature Bytes

The signature bytes are read by the same procedure as a normal verification of locations 030H and 031H, except that P3.6 and P3.7 need to be pulled to a logic low. The values are:
(030H) = 15H indicates manufactured by Philips
(031H) = 92H indicates 87C51

Program/Verify Algorithms

Any algorithm in agreement with the conditions listed in Table 8, and which satisfies the timing specifications, is suitable.

Security Bits

With none of the security bits programmed the code in the program memory can be verified. If the encryption table is programmed, the code will be encrypted when verified. When only security bit 1 (see Table 9) is programmed, MOVC instructions executed from external program memory are disabled from fetching code bytes from the internal memory, EA is latched on Reset and all further programming of the EPROM is disabled. When security bits 1 and 2 are programmed, in addition to the above, verify mode is disabled. When all three security bits are programmed, all of the conditions above apply and all external program memory execution is disabled.

Encryption Array

64 bytes of encryption array are initially unprogrammed (all 1s).

Table 8. EPROM Programming Modes

MODE	RST	$\overline{PSEN}$	ALE/PROG	$\overline{EA}/V_{PP}$	P2.7	P2.6	P3.7	P3.6
Read signature	1	0	1	1	0	0	0	0
Program code data	1	0	0*	V_{PP}	1	0	1	1
Verify code data	1	0	1	1	0	0	1	1
Pgm encryption table	1	0	0*	V_{PP}	1	0	1	0
Pgm security bit 1	1	0	0*	V_{PP}	1	1	1	1
Pgm security bit 2	1	0	0*	V_{PP}	1	1	0	0
Pgm security bit 3	1	0	0*	V_{PP}	0	1	0	1

NOTES:

1. '0' = Valid low for that pin, '1' = valid high for that pin.

2. $V_{PP} = 12.75 \text{ V} \pm 0.25 \text{ V}$.

3. $V_{CC} = 5 \text{ V} \pm 10\%$ during programming and verification.

* ALE/PROG receives 5 programming pulses for code data (also for user array; 5 pulses for encryption or security bits) while V_{PP} is held at 12.75 V. Each programming pulse is low for 100 μs ($\pm 10 \mu\text{s}$) and high for a minimum of 10 μs .

™Trademark phrase of Intel Corporation.

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

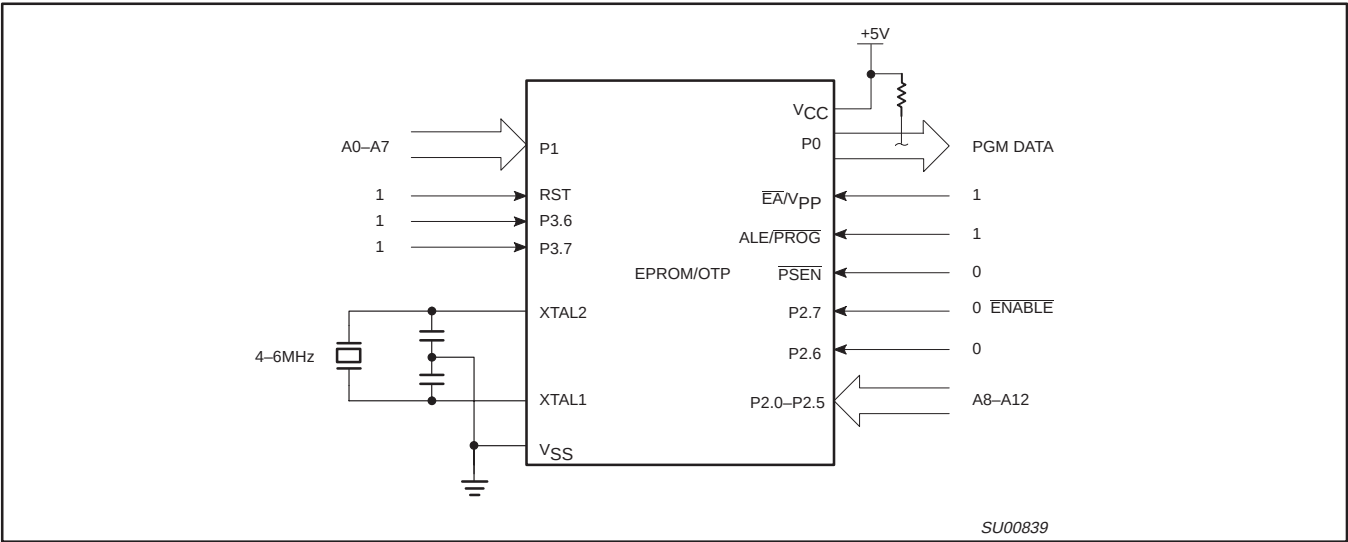


Figure 28. Program Verification

EPROM PROGRAMMING AND VERIFICATION CHARACTERISTICS

T_{amb} = 21°C to +27°C, V_{CC} = 5 V±10%, V_{SS} = 0 V (See Figure 29)

SYMBOL	PARAMETER	MIN	MAX	UNIT
V _{PP}	Programming supply voltage	12.5	13.0	V
I _{PP}	Programming supply current		50 ¹	mA
1/t _{CLCL}	Oscillator frequency	4	6	MHz
t _{AVGL}	Address setup to $\overline{\text{PROG}}$ low	48t _{CLCL}		
t _{GHAX}	Address hold after $\overline{\text{PROG}}$	48t _{CLCL}		
t _{DVGL}	Data setup to $\overline{\text{PROG}}$ low	48t _{CLCL}		
t _{GHDX}	Data hold after $\overline{\text{PROG}}$	48t _{CLCL}		
t _{EHS}	P2.7 ($\overline{\text{ENABLE}}$) high to V _{PP}	48t _{CLCL}		
t _{SHGL}	V _{PP} setup to $\overline{\text{PROG}}$ low	10		μs
t _{GHSL}	V _{PP} hold after $\overline{\text{PROG}}$	10		μs
t _{GLGH}	$\overline{\text{PROG}}$ width	90	110	μs
t _{AVQV}	Address to data valid		48t _{CLCL}	
t _{ELQZ}	$\overline{\text{ENABLE}}$ low to data valid		48t _{CLCL}	
t _{EHQZ}	Data float after $\overline{\text{ENABLE}}$	0	48t _{CLCL}	
t _{GHGL}	$\overline{\text{PROG}}$ high to $\overline{\text{PROG}}$ low	10		μs

NOTE:
1. Not tested.

80C51 8-bit microcontroller family
 4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
 low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

80C51 ROM CODE SUBMISSION

When submitting ROM code for the 80C51, the following must be specified:

1. 4k byte user ROM data
2. 64 byte ROM encryption key
3. ROM security bits.

ADDRESS	CONTENT	BIT(S)	COMMENT
0000H to 0FFFFH	DATA	7:0	User ROM Data
1000H to 103FH	KEY	7:0	ROM Encryption Key
1040H	SEC	0	ROM Security Bit 1
1040H	SEC	1	ROM Security Bit 2

Security Bit 1: When programmed, this bit has two effects on masked ROM parts:

1. External MOVC is disabled, and
2. $\overline{EA}$ is latched on Reset.

Security Bit 2: When programmed, this bit inhibits Verify User ROM.

NOTE: Security Bit 2 cannot be enabled unless Security Bit 1 is enabled.

If the ROM Code file does not include the options, the following information must be included with the ROM code.

For each of the following, check the appropriate box, and send to Philips along with the code:

- Security Bit #1: ☐ Enabled ☐ Disabled
- Security Bit #2: ☐ Enabled ☐ Disabled
- Encryption: ☐ No ☐ Yes If Yes, must send key file.

80C52 ROM CODE SUBMISSION

When submitting ROM code for the 80C52, the following must be specified:

1. 8k byte user ROM data
2. 64 byte ROM encryption key
3. ROM security bits.

ADDRESS	CONTENT	BIT(S)	COMMENT
0000H to 1FFFFH	DATA	7:0	User ROM Data
2000H to 203FH	KEY	7:0	ROM Encryption Key
2040H	SEC	0	ROM Security Bit 1
2040H	SEC	1	ROM Security Bit 2

Security Bit 1: When programmed, this bit has two effects on masked ROM parts:

1. External MOVC is disabled, and
2. $\overline{EA}$ is latched on Reset.

Security Bit 2: When programmed, this bit inhibits Verify User ROM.

NOTE: Security Bit 2 cannot be enabled unless Security Bit 1 is enabled.

If the ROM Code file does not include the options, the following information must be included with the ROM code.

For each of the following, check the appropriate box, and send to Philips along with the code:

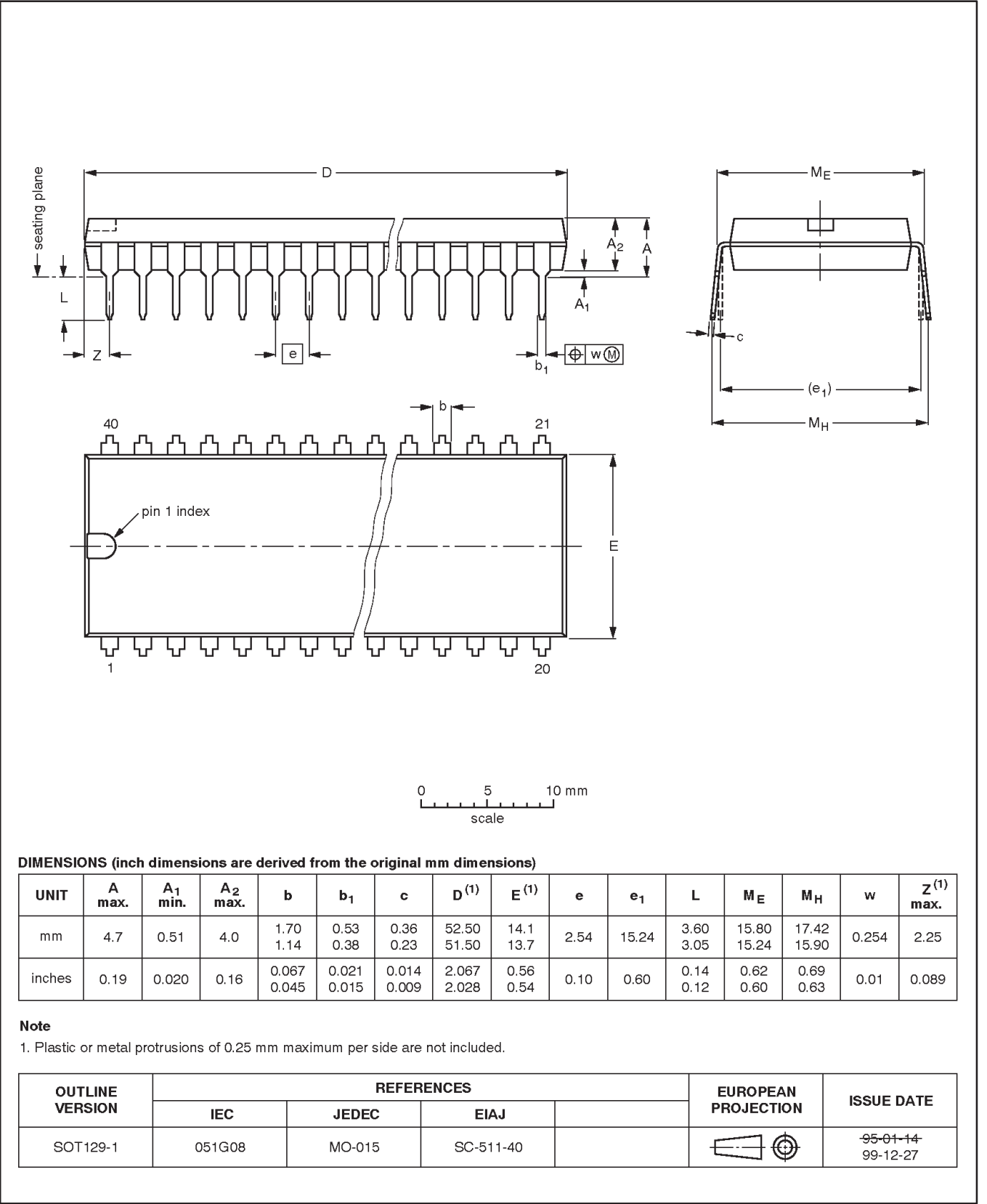
- Security Bit #1: ☐ Enabled ☐ Disabled
- Security Bit #2: ☐ Enabled ☐ Disabled
- Encryption: ☐ No ☐ Yes If Yes, must send key file.

80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

DIP40: plastic dual in-line package; 40 leads (600 mil)

SOT129-1



80C51 8-bit microcontroller family
4 K/8 K OTP/ROM low voltage (2.7 V–5.5 V),
low power, high speed (33 MHz), 128/256 B RAM

80C51/87C51/80C52/87C52

QFP44: plastic quad flat package; 44 leads (lead length 1.3 mm); body 10 x 10 x 1.75 mm

SOT307-2

